## NSN 5961-01-026-5373

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-026-5373 **Inclosure Material:** Glass **Overall Length:** Between 0.185 inches and 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.100 inches and 0.107 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 working peak reverse voltage, peak total value and 500.0 nonrepetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: